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Standard Recovery Diodes, (Stud Version), 85 A



DO-203AB (DO-5)

PRODUCT SUMMARY				
I _{F(AV)}	85 A			
Package	DO-203AB (DO-5)			
Circuit configuration	Single diode			

FEATURES

- High surge current capability
- Stud cathode and stud anode version



- · Leaded version available
- Types up to 1600 V V_{RRM}
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Battery chargers
- Converters
- Power supplies
- Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	85H	UNITS	
PARAMETER	1EST CONDITIONS	10 to 120	140 to 160	UNITS
1		85	85	А
I _{F(AV)}	T _C	140	110	°C
I _{F(RMS)}		133	133	А
1	50 Hz	1700	1700	A
I _{FSM}	60 Hz	1800	1800	A
l ² t	50 Hz	14 500	14 500	A ² s
1-1	60 Hz	13 500	13 500	A-S
V _{RRM}	Range	100 to 1200	1400 to 1600	V
T _J		-65 to +180	-65 to +150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$\begin{array}{c} I_{RRM} \ MAXIMUM \\ AT \ T_J = T_J \ MAXIMUM \\ mA \end{array}$	
	10	100	200		
	20	200	300		
	40	400	500		
VS-85HF(R)	60	600	700	9	
VS-86HF(R) VS-87HF(R)	80	800	900		
VS-88HF(R)	100	1000	1100		
	120	1200	1300		
	140	1400	1500	4.5	
	160	1600	1700	4.5	



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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			85HF(R)		
PARAMETER	STIVIBUL		TEST CONDITIONS			140/160	UNITS
Maximum average forward current	I _{F(AV)}	180° condu	ıction, half sine	wave	8		Α
at case temperature	. (,				140	110	°C
Maximum RMS forward current	I _{F(RMS)}				133		Α
		t = 10 ms	No voltage		1700		
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied	Sinusoidal half wave,	18	00	_ \
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1450		A
		t = 8.3 ms	reapplied		1500		
	l ² t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	14 500		- A ² s
		t = 8.3 ms	reapplied		13 500		
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		10 500		
		t = 8.3 ms	reapplied		9400		
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied		16	000	A ² √s	
Value of threshold voltage (up to 1200 V)	V	V			0.0	68	V
Value of threshold voltage (for 1400 V, 1600 V)	V _{F(TO)}	$T_J = T_J$ maximum		0.0	69		
Value of forward slope resistance (up to 1200 V)	- r _f		T. T. massimous		1.0	62	mW
Value of forward slope resistance (for 1400 V, 1600 V)		$T_J = T_J$ maximum		1.	75	11100	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 267 A$	$T_J = 25 ^{\circ}\text{C}, t_D =$	= 400 µs rectangular wave	1.2	1.4	V

THERMAL AND MECHANICAL SPECIFICATIONS					
DADAMETED	OVADOL	TEST CONDITIONS	85H		
PARAMETER	SYMBOL		10 to 20	140 to 160	UNITS
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-65 to +180	-65 to +150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.	0.35	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		K/W
Maximum shock (1)			1500		
Maximum constant vibration (1)		50 Hz 20		.0	g
Maximum constant acceleration (1)		Stud outwards	5000		
		Not lubricated thread, tighting on nut	3.4 (30)		
Maximum allowable mounting torque		Lubricated thread, tighting on nut	2.3 (20)		N·m
+ 0 %, - 10 %		Not lubricated thread, tighting on hexagon	4.2 (37)		(lbf · in)
		Lubricated thread, tighting on hexagon	3.2	(28)	
Ain-atin-t		Unleaded device	1	7	g
Approximate weight		Onleaded device	0	.6	oz.
Case style		See dimensions - link at the end of datasheet DO-203AB (DO-		203AB (DO-5)

Notes

- (1) Available only for 88HF
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks

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△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.10	0.08			
120°	0.11	0.11			
90°	0.13	0.13	$T_J = T_J$ maximum	K/W	
60°	0.17	0.17			
30°	0.26	0.26			

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

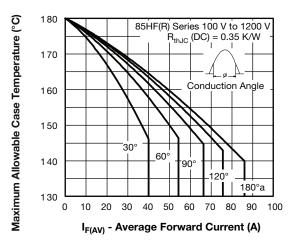


Fig. 1 - Current Ratings Characteristics

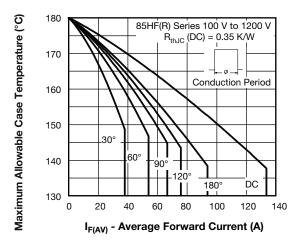


Fig. 2 - Current Ratings Characteristics

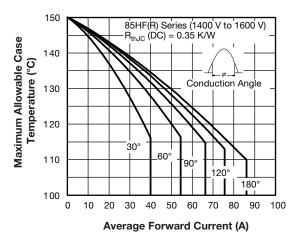


Fig. 3 - Current Ratings Characteristics

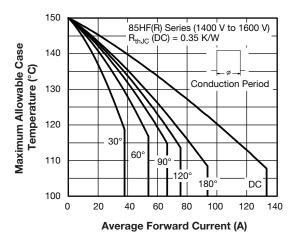


Fig. 4 - Current Ratings Characteristics

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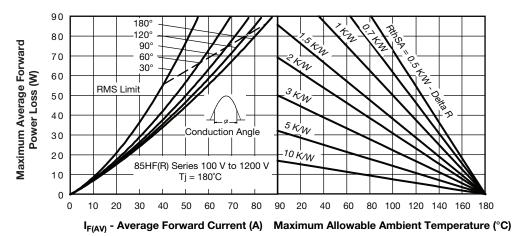


Fig. 5 - Forward Power Loss Characteristics

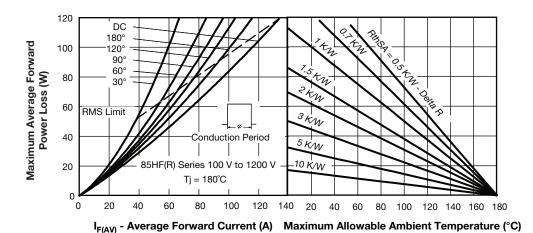


Fig. 6 - Forward Power Loss Characteristics

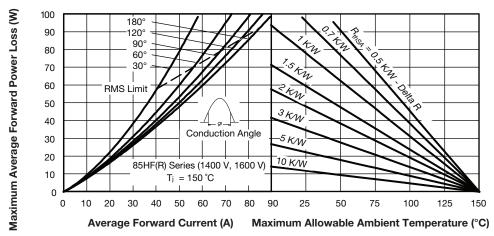


Fig. 7 - Forward Power Loss Characteristics

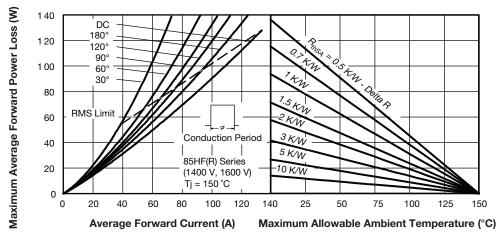


Fig. 8 - Forward Power Loss Characteristics

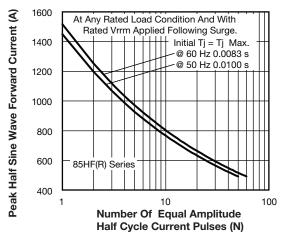


Fig. 9 - Maximum Non-Repetitive Surge Current

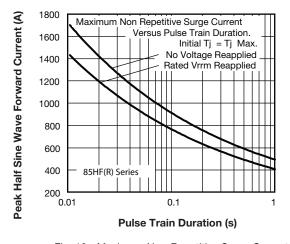


Fig. 10 - Maximum Non-Repetitive Surge Current

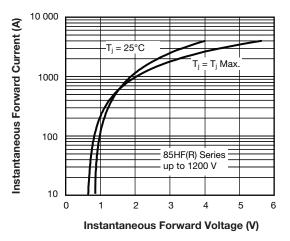


Fig. 11 - Forward Voltage Drop Characteristics

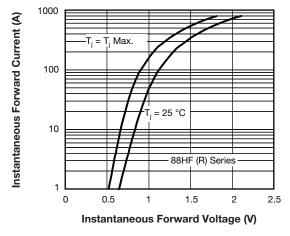


Fig. 12 - Forward Voltage Drop Characteristics

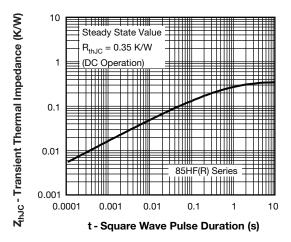
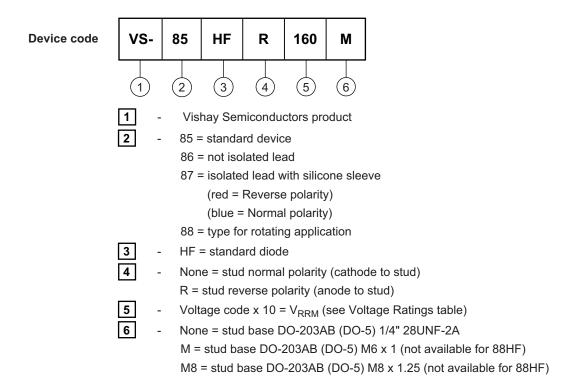


Fig. 13 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE



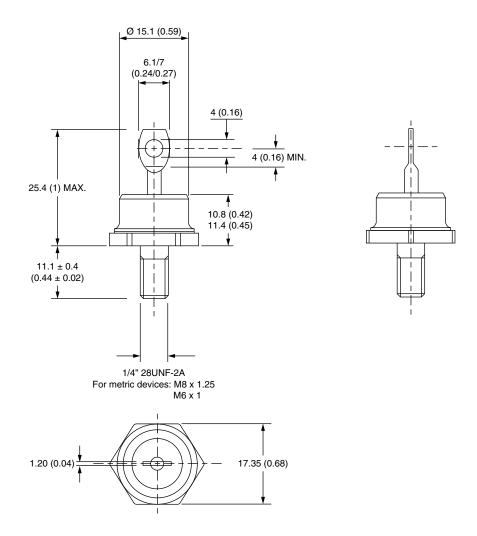
LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?95342</u>			



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DO-203AB (DO-5) for 85HF(R) and 86HF(R) Series

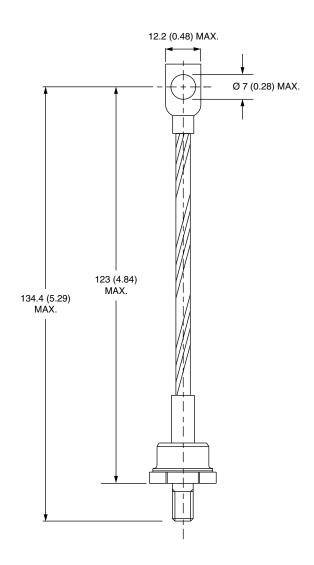
DIMENSIONS in millimeters (inches)





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DIMENSIONS FOR 86HF (R) SERIES in millimeters (inches)





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